Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-303-4843

	nline at https://aerobasegroup.com/nsn/5961-01-303-4843
Inclosu	ure Material:
Glass	
Overall	I Length:
0.200 ir	nches
Termin	nal Length:
1.000 ir	nches
Overall	I Diameter:
0.090 ir	nches
Functio	on For Which Designed:
Zener d	diode
Joint E	Electronic Device Engineering Council/jedec/case Outline Designation:
Do-35	
Mounti	ing Method:
Termina	al
Semico	onductor Material:
Silicon	
Voltage	e Rating In Volts Per Characteristic:
4.3 reę	gulator voltage
Voltage	e Tolerance In Percent:
-5.0/+5.	.0
Curren	at Rating Per Characteristic:
20.00 m	nilliamperes source cutoff current horsepower metric and 99.00 milliamperes repetitive peak forward current
Power	Rating Per Characteristic:
500.0 m	nilliwatts small-signal input power, common-collector preset
Maxim	um Operating Tempurature Per Measurement Point:
175.0 d	degrees celsius ambient air
Test Da	ata Document:
81349-r	mil-s-19500 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification
format;	excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain
environ	mental and performance requirements and test conditions that are shown as "typical", "average", "", etc.).
Termin	nal Type And Quantity:
2 unins	sulated wire lead
Specifi	ication Data:
81349-r	mil-s-19500/533 government specification
Shelf L	.ife:
N/a	
Unit Of	f Measure:

Demilitarization:

No

Fiig:

A110a0